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N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY						
V _{DS} (V)	$R_{DS(on)}(m\Omega)(Typ.)$	I _D (A) ^a	Q _g (Typ.)			
60	4.0 at V _{GS} = 10 V	72	38 nC			
00	5.7 at V _{GS} = 4.5 V	12				

FEATURES



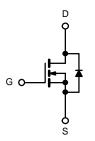
- DT-SJ Power MOSFET
- 100 % Rg and UIS tested
- AEC-Q101 Qualified for Automotive Applications

APPLICATIONS

- · Notebook PC Core
- VRM/POL

DFN5X6-8L Pin Configuration





N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS (T _C = 25 °C, unless otherwise noted)						
PARAMETER		SYMBOL	LIMIT	UNIT		
Drain-Source Voltage	V _{DS}	60	V			
Gate-Source Voltage	V _{GS}	± 20	V			
Continuous Drain Current /T 475 9C\3	T _C = 25 °C		72	А		
Continuous Drain Current (T _J = 175 °C) ^a	T _C = 100 °C	I _D	59			
Pulsed Drain Current ^b	I _{DM}	280				
Single Avalanche Energy	E _{AS}	205	mJ			
Maximum Power Dissipation ^c	T _C = 25 °C	В	108	W		
Maximum Fower Dissipation	T _C = 100 °C	P _D	54			
Operating Junction and Storage Temperature Ra	T _J , T _{stg}	- 55 to 175	°C			

THERMAL RESISTANCE RATINGS					
PARAMETER	SYMBOL	LIMIT	UNIT		
Junction-to-Ambient (PCB Mount) ^d	R _{thJA}	55	°C/W		
Junction-to-Case (Drain)	R _{thJC}	1.38] C/VV		

Notes

- a. Calculated continuous current based on maximum allowablejunction temperature.
- b. Repetitive rating; pulse width limited by max. junction temperature.
- c. Pd is based on max. junction temperature, using junction-case thermal resistance.
- d. The value of R_{8JA} is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper,in a still air environment with Ta=25 °C.

SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)							
PARAMETER	SYMBOL	DL TEST CONDITIONS		TYP.	MAX.	UNIT	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$	60	-			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$	1	-	3	V 3	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	± 100	μΑ	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 60 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	1	μA	
Zero Gate Voltage Drain Current		$V_{DS} = 48 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 \text{ °C}$	-	-	10		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 10 \text{ V}$	72	-	-	Α	
Drain-Source On-State Resistance ^a	D	V _{GS} = 10 V, I _D = 10 A	-	4.0	4.8	m- 0	
Diam-Source On-State Resistance	R _{DS(on)}	V _{GS} = 4.5 V, I _D = 10 A	-	5.7	7.5	mΩ	
Forward Transconductance ^a g_{fs} $V_{DS} = 4$.		V _{DS} = 4.5 V, I _D = 10 A	-	60	-	S	
Dynamic ^b							
Input Capacitance	C _{iss}		-	2220	-	pF	
Output Capacitance	C _{oss}	$V_{GS} = 0 \text{ V}, V_{DS} = 30 \text{ V}, f = 1 \text{ MHz}$	-	585	-		
Reverse Transfer Capacitance	C _{rss}		-	8	-		
Total Gate Charge ^c	Q_g		-	38	-	nC	
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 30 \text{ V}, V_{GS} = 10 \text{ V}, I_{D} = 10 \text{ A}$	-	4.3	-		
Gate-Drain Charge ^c	Q_{gd}		-	6.4	-		
Gate Resistance	R_g	f = 1 MHz	-	1.8	-	Ω	
Turn-On Delay Time ^c	t _{d(on)}		-	10	-		
Rise Time ^c	t _r	$V_{DD} = 30 \text{ V}, \text{ RGEN} = 3 \Omega,$	-	13	-	- ns	
Turn-Off Delay Time ^c	t _{d(off)}	Vgs = 10 V, ID= 10 A	-	30	-		
Fall Time ^c	t _f		-	15	-		
Drain-Source Body Diode Ratings and Characteristics ^b (T _J = 25 °C)							
Continuous Source-Drain Diode Current	I _S	T _C = 25 °C	-	-	72	Α	
Pulsed Current	I _{SM}		-	-	280	Α	
Forward Voltage ^a	V _{SD}	I _F = 1 A, V _{GS} = 0 V	-	0.7	-	V	
Reverse Recovery Time	t _{rr}	I _F = 20 A, di/dt = 100 A/µs	-	33	-	ns	
Reverse Recovery Charge	Q _{rr}	if = 20 A, αί/αι = 100 A/μs	-	31	-	nC	

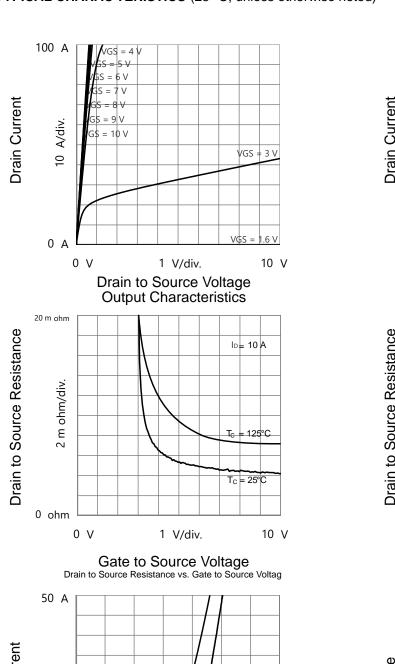
Notes

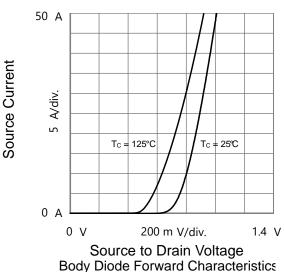
- a. Pulse test; pulse width ≤ 300 µs, duty cycle ≤ 2 %.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

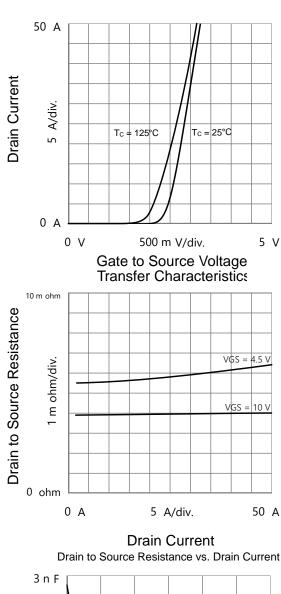
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those in dicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended pe riods may affect device reliability.



TYPICAL CHARAC TERISTICS (25 °C, unless otherwise noted)





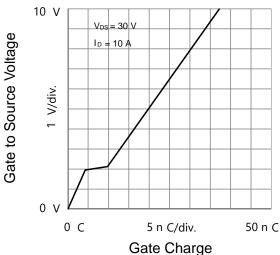


O V 10 V/div. 60 V

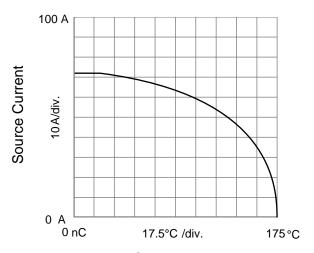
Drain to Source Voltage Capacitances



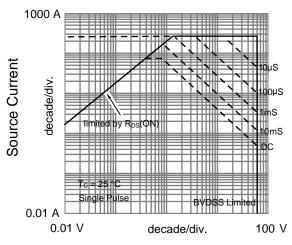
TYPICAL CHARAC TERISTICS (25 °C, unless otherwise noted)



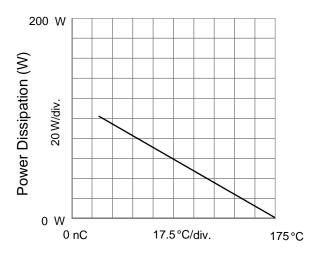
Gate to Source Voltage vs. GateCharge



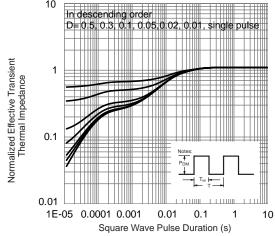
T_C - Case Temperature



Source to Drain Voltage Safe Operating Area, Junction-to-Case



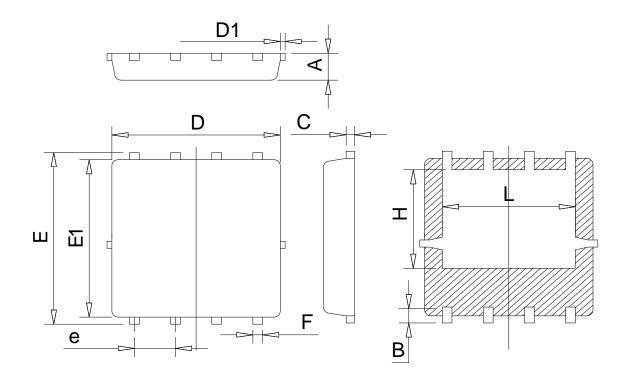
T_C - Case Temperature



Normalized Thermal Transient Impedance, Junction-to-Case



DFN5X6-8L PACKAGE OUTLINE



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)

Symbol	Min	Тур	Max
Α	0.78	0.95	1.12
В	0.45	0.58	0.78
С	0.18	0.254	0.36
D	4.70	5.20	5.45
D1			0.18
Е	5.85	6.05	6.25
E1	5.38	5.55	5.98
е	1.15	1.27	1.40
F	0.18	0.30	0.52
Н	3.25	3.47	3.70
L	3.75	4.00	4.25





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